2SC5363J

Silicon NPN epitaxial planar type

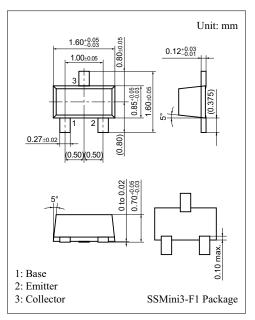
For low-voltage high-frequency amplification

Features

- \bullet High transfer ratio f_{T}
- Small collector output capacitance (Common base, input open circuited) C_{ob}
- SS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit				
Collector-base voltage (Emitter open)	V _{CBO}	9	V				
Collector-emitter voltage (Base open)	V _{CEO}	6	V				
Emitter-base voltage (Collector open)	V _{EBO}	2	V				
Collector current	I _C	30	mA				
Collector power dissipation	P _C	125	mW				
Junction temperature	Tj	125	°C				
Storage temperature	T _{stg}	-55 to +125	°C				



Marking Symbol : 3Y

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 5 V, I_E = 0$			1	μΑ
Emitter-base cut-off current (Collector open)	I _{EBO}	$V_{EB} = 1 V, I_C = 0$			1	μΑ
Forward current transfer ratio	\mathbf{h}_{FE}	$V_{CE} = 3 V, I_C = 10 mA$	40		160	_
Transition frequency	f_{T}	$V_{CE} = 3 \text{ V}, I_C = 10 \text{ mA}, f = 1.5 \text{ GHz}$		10		GHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 3 V, I_E = 0, f = 1 MHz$		0.4	0.7	pF
Forward transfer gain	S21e ²	$V_{CE} = 0.3 \text{ V}, I_C = 1 \text{ mA}, f = 0.9 \text{ GHz}$		6.5		dB
Noise figure	NF	$V_{CE} = 0.3 \text{ V}, I_C = 1 \text{ mA}, f = 0.9 \text{ GHz}$		1.7		dB

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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